

# MP3397 Step-Up, 4-String Max 350mA/String White LED Driver

### **DESCRIPTION**

The MP3397 is a step-up controller with 4 current channels designed to drive WLED arrays for large-size LCD-panel backlighting applications. The MP3397 is flexible, and can expand the number of LED channels with two or more MP3397s in parallel operating from a single inductive power source.

The MP3397 uses current-mode fixed-frequency architecture. An external resistor sets the switching frequency. This signal drives an external MOSFET to boost up the output voltage from 5V to a 28V input supply. The MP3397 regulates the current in each LED string to the programmed value set by an external current-setting resistor.

The MP3397 applies 4 internal current sources for current balance. The current matching can achieve 2.5% regulation accuracy between strings. Its low regulation voltage on LED current sources reduces power loss and improves efficiency.

An external PWM input signal or DC input signal controls PWM dimming. The dimming PWM signal can be generated internally and the dimming frequency is programmed by an external setting capacitor.

#### **FEATURES**

- 4-String, Max 350mA/String at 10% D<sub>PWM</sub>
- 5V to 28V Input Voltage Range
- 2.5% Current Matching Accuracy Between Strings
- Programmable Switching Frequency
- PWM or DC Input Burst PWM Dimming
- Open and Short LED Protection
- Programmable Over-Voltage Protection
- Cascading Capability with a Single Power Source
- Under-Voltage Lockout
- Thermal Shutdown
- 16-pin SOIC Package

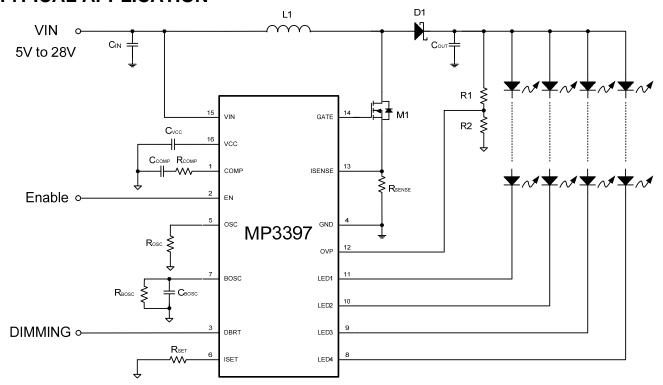
#### **APPLICATIONS**

- Desktop LCD Flat Panel Displays
- Flat Panel Video Displays
- 2D/3D LCD TVs and Monitors

All MPS parts are lead-free and adhere to the RoHS directive. For MPS green status, please visit MPS website under Quality Assurance. "MPS" and "The Future of Analog IC Technology" are Registered Trademarks of Monolithic Power Systems, Inc.



# **TYPICAL APPLICATION**



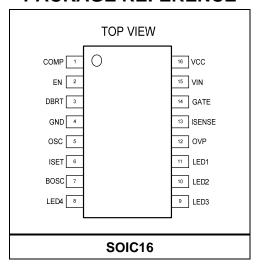


#### ORDERING INFORMATION

Part Number	Package	Top Marking
MP3397ES*	SOIC16	MP3397

\*For Tape & Reel, add suffix –Z (eg. MP3397ES–Z). For RoHS compliant packaging, add suffix –LF (eg. MP3397ES–LF–Z)

#### PACKAGE REFERENCE



# **ABSOLUTE MAXIMUM RATINGS (1)**

VIN	0.3V to +30V
V <sub>GATE</sub>	0.5V to +6.8V
VCC	0.5V to +6.8V
$V_{\text{LED1}}$ to $V_{\text{LED4}}$	1V to +55V
All Other Pins	0.3V to +6.3V
Continuous Power Dissipation	$(T_A = 25^{\circ}C)^{(2)}$
SOIC16	1.56 W
Junction Temperature	150°C
Lead Temperature	260°C
Storage Temperature	65 °C to +150°C

# Recommended Operating Conditions (3)

Thermal Resistance (4)	$oldsymbol{ heta}_{JA}$	$oldsymbol{ heta}_{JC}$	
SOIC16	80	35	.°C/W

#### Notes:

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature  $\mathsf{T}_\mathsf{J}$  (MAX), the junction-to-ambient thermal resistance  $\theta_\mathsf{JA}$ , and the ambient temperature  $\mathsf{T}_\mathsf{A}.$  The maximum allowable continuous power dissipation at any ambient temperature is calculated by  $\mathsf{P}_\mathsf{D}$  (MAX) = ( $\mathsf{T}_\mathsf{J}$  (MAX)- $\mathsf{T}_\mathsf{A}$ )/ $\theta_\mathsf{JA}.$  Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- The device is not guaranteed to function outside of its operation conditions.
- 4) Measured on JESD51-7, 4-layer PCB.



# **ELECTRICAL CHARACTERISTICS**

 $V_{IN}$  =12V,  $V_{EN}$  = 5V,  $T_A$  = 25°C, unless otherwise noted.

Parameters	Symbol	Condition	Min	Тур	Max	Units
Operating Input Voltage	V <sub>IN</sub>		5		28	V
Supply Current (Quiescent)	IQ	$V_{IN}$ =12V, $V_{EN}$ =5V, no load with switching		4		mA
Supply Current (Shutdown)	I <sub>ST</sub>	V <sub>EN</sub> =0V, V <sub>IN</sub> =12V			2	μΑ
LDO Output Voltage	V <sub>CC</sub>	V <sub>EN</sub> =5V, 7V <v<sub>IN&lt;28V, 0<i<sub>VCC&lt;10mA</i<sub></v<sub>	5.5	6	6.5	V
Input UVLO Threshold	$V_{IN\_UVLO}$	Rising Edge	3.8	4.2	4.6	V
Input UVLO Hysteresis				200		mV
EN High Voltage	V <sub>EN_HIGH</sub>	V <sub>EN</sub> Rising	1.8			V
EN Low Voltage	$V_{EN\_LOW}$	V <sub>EN</sub> Falling			0.6	V
STEP-UP CONVERTER		1	I.			l
Gate Driver Impedance (Sourcing)		V <sub>CC</sub> =6V,V <sub>GATE</sub> =6V		4		Ω
Gate Driver Impedance (Sinking)		V <sub>CC</sub> =6V,I <sub>GATE</sub> =10mA		2		Ω
Switching Frequency	f <sub>SW</sub>	$R_{OSC}$ = 115k $\Omega$	480	540	600	kHz
Ownering Frequency		$R_{OSC}$ = 374k $\Omega$	145	165	185	kHz
OSC Voltage	Vosc		1.20	1.23	1.26	V
Minimum On Time	t <sub>ON_MIN</sub>	PWM Mode, when no pulse skipping happens		100		ns
Maximum Duty Cycle	$D_{MAX}$		90			%
ISENSE Limit		Max Duty Cycle	150	200	250	mV
COMP Source Current Limit	I <sub>COMP SOLI</sub>			65		μA
COMP Sink Current Limit	I <sub>COMP SILI</sub>			15		μA
PWM DIMMING						
DBRT Leakage Current	I <sub>DBRT_LK</sub>		-5		5	μΑ
BOSC Frequency	f <sub>BOSC</sub>	C <sub>BOSC</sub> =2.2nF	1.0	1.5	2	kHz
BOSC Output Current	I <sub>BOSC</sub>		6	7.5	9	μA
LED CURRENT REGULATION						
ISET Voltage	V <sub>ISET</sub>		1.20	1.23	1.25	V
LEDX Average Current	I <sub>LED</sub>	R <sub>ISET</sub> =30kΩ	31	32	33	mA
Current Matching (5)		I <sub>LED</sub> =32mA			2.5	%



# ELECTRICAL CHARACTERISTICS (continued)

 $V_{IN}$  =12V,  $V_{EN}$  = 5V,  $T_A$  = 25°C, unless otherwise noted.

Parameters	Symbol	Condition	Min	Тур	Max	Units	
LEDX Regulation Voltage	$V_{LEDX}$	I <sub>LED</sub> =180mA		390		mV	
PROTECTION	PROTECTION						
OVP(Over Voltage Protection) Threshold	V <sub>OVP_OV</sub>	Rising Edge	1.20	1.23	1.26	V	
OVP UVLO threshold	V <sub>OVP_UV</sub>	Step-up Converter Fails	50	70	90	mV	
LEDX UVLO Threshold	$V_{LEDX\_UV}$		156	196	236	mV	
LEDX Over Voltage Threshold	$V_{LEDX\_OV}$		5.8	6.3	6.8	V	
Thermal Shutdown Threshold	T <sub>ST</sub>			150		°C	

#### Notes:

<sup>5)</sup> Matching is defined as the difference of the maximum to minimum current divided by 2 times average currents.



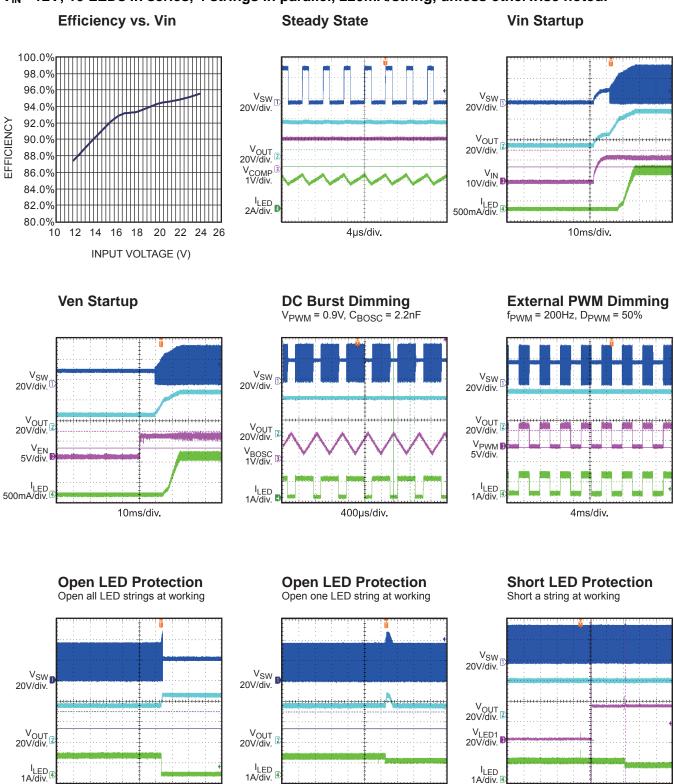
# **PIN FUNCTIONS**

Pin #	Name	Description
1	COMP	Step-up Converter Compensation Pin. This pin compensates the regulation control loop. Connect a ceramic capacitor from COMP to GND.
2	EN	Enable Control Input. Turn-on threshold at 1.8V. Turn-off threshold at 0.6 V. Do not let this pin float.
3	DBRT	Brightness Control Input. Apply a PWM signal on this pin for for external PWM dimming mode. Apply a DC voltage range from 0.2V to 1.2V on this pin to linearly set the internal dimming duty cycle from 0% to 100% for DC-input PWM dimming mode. The MP3397 has positive dimming polarity on DBRT.
4	GND	Ground.
5	osc	Switching Frequency Set. Connect a resistor between OSC and GND to set the step-up converter switching frequency. The voltage at this pin is regulated to 1.23V. The clock frequency is proportional to the current sourced from this pin.
6	ISET	LED Current Set. Tie a current-setting resistor from this pin to ground to program the current in each LED string. This pin voltage is regulated to 1.23V. The LED current is proportional to the current through the ISET resistor.
7	BOSC	Dimming Repetition Set. This is the timing pin for the oscillator to set the dimming frequency. To use DC input PWM dimming mode, connect a capacitor from this pin to GND to set the internal dimming frequency. A saw-tooth waveform is generated on this pin. To use external PWM dimming mode, connect a resistor from this pin to GND, and apply the PWM signal on DBRT pin.
8	LED4	LED String 4 Current Input. This pin is the open-drain output of an internal dimming control switch. Connect the LED String 4 cathode to this pin.
9	LED3	LED String 3 Current Input. This pin is the open-drain output of an internal dimming control switch. Connect the LED String 3 cathode to this pin.
10	LED2	LED String 2 Current Input. This pin is the open-drain output of an internal dimming control switch. Connect the LED String 2 cathode to this pin.
11	LED1	LED String 1 Current Input. This pin is the open-drain output of an internal dimming control switch. Connect the LED String 1 cathode to this pin.
12	OVP	Over-Voltage Protection Input. Connect a resistor divider from output to this pin to program the OVP threshold. When this pin voltage reaches 1.23V, the MP3397 triggers Over Voltage Protection mode.
13	ISENSE	Current Sense Input. During normal operation, this pin senses the voltage across the external-inductor current-sensing resistor ( $R_{\text{SENSE}}$ ) for peak-current-mode control and also to limit the inductor current during every switching cycle. If this pin is not used for cascading applications, tie this pin to GND; do not let this pin float.
14	GATE	Step-up Converter Power Switch Gate Output. This pin drives the external power N-MOS device.
15	VIN	Supply Input. VIN supplies the power to the chip, as well as the step-up converter switch. Drive VIN with a 5V to 28V power source. Must be locally bypassed.
16	VCC	The Internal 6V Linear Regulator Output. VCC provides power supply for the external MOSFET switch gate driver and the internal control circuitry. Bypass VCC to GND with a ceramic capacitor.



#### TYPICAL PERFORMANCE CHARACTERISTICS

V<sub>IN</sub> =12V, 10 LEDs in series, 4 strings in parallel, 220mA/string, unless otherwise noted.



4ms/div.

10ms/div.

10ms/div.



## **FUNCTIONAL BLOCK DIAGRAM**

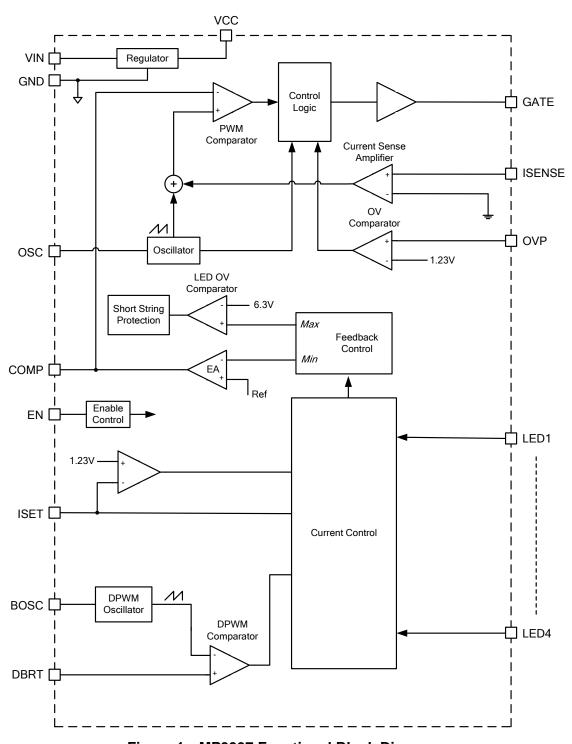


Figure 1—MP3397 Functional Block Diagram



#### **OPERATION**

The MP3397 employs a programmable constant-frequency, peak-current—mode step-up converter with 4 channels or regulated current sources to drive an array of up to 4 strings of white LEDs.

#### **Internal 6V Regulator**

The MP3397 includes an internal linear regulator (VCC). When VIN is greater than 6.5V, this regulator outputs a 6V power supply to the external MOSFET switch gate driver and the internal control circuitry. The VCC voltage drops to 0V when the chip shuts down. The MP3397 features under-voltage lockout (UVLO). The chip is disabled until VCC exceeds the UVLO threshold. The UVLO hysteresis is approximately 200mV.

#### **System Startup**

When enabled, the MP3397 checks the topology connection first. The chip monitors the overvoltage protection (OVP) pin to see if the Schottky diode is not connected or if the boost output is shorted to GND. An OVP voltage of less than 70mV will disable the chip. The MP3397 also checks other safety limits, including UVLO and over-temperature protection (OTP) after passing the OVP test. If all the protection tests pass, the chip then starts boosting the step-up converter with an internal soft-start.

The enable signal must occur after the establishment of the input voltage and PWM dimming signal during the start-up sequence.

#### **Step-Up Converter**

The converter operating frequency is programmable (from 150kHz to 500kHz) with an external set resistor on the OSC pin. This flexibility helps to optimize the size of external components and improve the efficiency.

At the beginning of each cycle, the internal clock turns on the external MOSFET. A stabilizing ramp added to the output of the current sense amplifier prevents sub-harmonic oscillations for duty cycles greater than 50 percent. This result is fed into the PWM comparator. When this resulting voltage rises to the level of the error amplifier output voltage ( $V_{\text{COMP}}$ ), the external MOSFET turns off.

The output voltage of the internal error amplifier is an amplified signal of the difference between the reference voltage and the feedback voltage. The converter automatically chooses the lowest active LEDX pin voltage to provide a highenough bus voltage to power all the LED arrays.

If the feedback voltage drops below the reference, the output of the error amplifier increases. This result in more current flowing through the MOSFET, thus increasing the power delivered to the output. This forms a closed loop that regulates the output voltage.

Under light-load operation—where  $V_{OUT} \approx VIN$ —the converter runs in pulse-skipping mode where the MOSFET turns on for a minimum on-time of approximately 100ns, and then the converter discharges the power to the output for the remaining period. The external MOSFET remains off until the output voltage needs to be boosted again.

#### **Dimming Control**

The MP3397 provides two PWM dimming methods: external PWM signal or DC-input PWM dimming mode (see Figure 2).

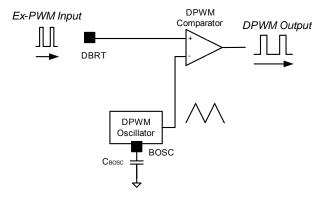


Figure 2—PWM Dimming Method



For external PWM dimming, ground the BOSC pin through a resistor, and apply an external PWM signal to the DBRT pin.

For DC-input PWM dimming, apply a DC analog signal to the DBRT pin, and connect a capacitor from BOSC to ground. The DC signal is then converted to a DPWM dimming signal with a proportional oscillation frequency.

The brightness of the LED array is proportional to the duty cycle of the DPWM signal. The DPWM signal frequency is set by the capacitor from the BOSC pin to ground.

#### **Open String Protection**

Open string protection is achieved through the OVP pin and the LED (1 to 4) pins. If one or more strings are open, the respective LEDX pins are pulled to ground and the IC keeps charging the output voltage until it reaches the over-voltage protection (OVP) threshold. Then the chip marks which strings have an LEDX pin voltage lower than 196mV. Once marked, the remaining LED strings force the output voltage back into tight regulation. The string with the largest voltage drop determines the output regulation.

The MP3397 will always attempt to light at least one string. If all strings are open, the MP3397 shuts down the step-up converter. The strings will remain in this marked state until the chip reset.

#### **Short String Protection**

The MP3397 monitors the LEDX pin voltages to determine if a short string fault has occurred. If more strings are shorted. corresponding LEDX pins tolerate this higher voltage. If an LEDX pin voltage is higher than 6.3V, this condition triggers the detection of a short string. When a short string fault (LEDX over-voltage fault) continues for 4096 switching cycles, the fault string is marked OFF and disabled. Once a string is marked OFF, it disconnects from the output voltage loop. The marked LED strings shut off completely until the part restarts. If all strings are shorted, the MP3397 will shut down the step-up converter. The strings remain marked OFF until the chip resets.



#### APPLICATION INFORMATION

#### **Selecting the Switching Frequency**

Set the switching frequency of the step-up converter from 150kHz to 500kHz for most applications. An oscillator resistor on OSC pin sets the internal oscillator frequency for the step-up converter according to the equation:

$$f_{\text{SW}}(kHz) = \frac{62100}{\text{Rosc}(k\Omega)}$$

For  $R_{OSC}$ =330k $\Omega$ , the switching frequency is set to 188kHz.

#### **Setting the LED Current**

The LED string currents are identical and set through the current setting resistor on the ISET pin.

$$I_{LED}(mA) = \frac{790 \times 1.23V}{(R_{SET} + 0.4)k\Omega}$$

For  $R_{\text{SET}}$ =7.68k $\Omega$ , the LED current is set to 120mA. The ISET pin can not be open.

#### **Selecting the Input Capacitor**

The input capacitor reduces the surge current drawn from the input supply and the switching noise from the device. The input capacitor impedance at the switching frequency should be less than the input source impedance to prevent the high-frequency switching current from passing through to the input. Use ceramic capacitors with X5R or X7R dielectrics for their low ESR and small temperature coefficients. For most applications, use a 4.7µF ceramic capacitor in parallel with a 220µF electrolytic capacitor.

# Selecting the Inductor and Current Sensing Resistor

The MP3397 requires an inductor to supply a higher output voltage while being driven by the input voltage. A larger value inductor results in less ripple current, resulting in lower peak inductor current and reducing stress on the internal N-channel MOSFET. However, larger-value inductors have a larger physical size, higher series resistance, and lower saturation current.

Choose an inductor that does not saturate under the worst-case load conditions. Select the minimum inductor value to ensure that the boost converter works in continuous conduction mode with high efficiency and good EMI performance. Calculate the required inductance value using the equation:

$$\begin{split} L \geq \frac{\eta \times V_{\text{OUT}} \ \times \ D \times (1\!\!-\!D)^2}{2 \times \ f_{\text{SW}} \ \times \ I_{\text{LOAD}}} \\ D = 1 - \frac{V_{IN}}{V_{\text{OUT}}} \end{split}$$

Where  $V_{IN}$  and  $V_{OUT}$  are the input and output voltages,  $f_{SW}$  is the switching frequency,  $I_{LOAD}$  is the LED load current, and  $\eta$  is the efficiency.

The switching current is usually used for the peak current mode control. In order to avoid hitting the current limit, the voltage across the sensing resistor  $R_{\text{SENSE}}$  must measure less than 80% of the worst-case current-limit voltage,  $V_{\text{SENSE}}$ .

$$\begin{split} R_{\text{SENSE}} &= \frac{0.8 \times V_{\text{SENSE}}}{I_{\text{L(PEAK)}}} \\ I_{\text{L(PEAK)}} &= \frac{V_{\text{OUT}} \times I_{\text{LOAD}}}{\eta V_{\text{IN}}} + \frac{V_{\text{IN}} \times (V_{\text{OUT}} \text{-} V_{\text{IN}})}{2 \times L \times f_{\text{SW}} \times V_{\text{OUT}}} \end{split}$$

Where  $I_{L(PEAK)}$  is the peak value of the inductor current.  $V_{SENSE}$  is shown in Figure 3.

#### Vsense vs. Duty Cycle

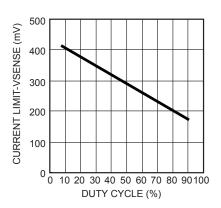


Figure 3—V<sub>SENSE</sub> vs Duty Cycle

#### **Selecting the Power MOSFET**

The MP3397 is capable of driving a wide variety of N-channel power MOSFETS. The critical parameters of selection of a MOSFET are:

- 1. Maximum drain-to-source voltage, VDS(MAX)
- 2. Maximum current, ID(MAX)
- 3. On-resistance, RDS(ON)
- 4. Gate source charge QGS and gate drain charge QGD



#### 5. Total gate charge, QG

Ideally, the off-state voltage across the MOSFET is equal to the output voltage. Considering the voltage spike when it turns off,  $V_{\text{DS}(\text{MAX})}$  should be greater than 1.5 times of the output voltage.

The maximum current through the power MOSFET occurs at the maximum input voltage and the maximum output power. The maximum RMS current through the MOSFET is given by

$$I_{\text{RMS(MAX)}} = I_{\text{IN(MAX)}} \times \sqrt{D_{\text{MAX}}}$$
 , where: 
$$D_{\text{MAX}} \approx \frac{V_{\text{OUT}} - V_{\text{IN(MIN)}}}{V_{\text{OUT}}}$$

The current rating of the MOSFET should be greater than  $1.5 x I_{\text{RMS}}$ 

The ON resistance of the MOSFET determines the conduction loss, which is given by:

$$P_{cond} = I_{RMS}^2 \times R_{DS(on)} \times k$$

Where k is the temperature coefficient of the MOSFET.

The switching loss is related to  $Q_{\text{GD}}$  and  $Q_{\text{GS1}}$  which determine the commutation time.  $Q_{\text{GS1}}$  is the charge between the threshold voltage and the plateau voltage when a driver charges the gate, which can be read in the chart of  $V_{\text{GS}}$  vs.  $Q_{\text{G}}$  of the MOSFET datasheet.  $Q_{\text{GD}}$  is the charge during the plateau voltage. These two parameters are needed to estimate the turn-on and turn-off losses.

$$\begin{split} P_{SW} \; &= \frac{Q_{GS1} \times R_G}{V_{DR} - V_{TH}} \times V_{DS} \times I_{IN} \times f_{SW} \; + \\ &\frac{Q_{GD} \times R_G}{V_{DR} - V_{PLT}} \times V_{DS} \times I_{IN} \times f_{SW} \end{split}$$

Where  $V_{TH}$  is the threshold voltage,  $V_{PLT}$  is the plateau voltage,  $R_G$  is the gate resistance, and  $V_{DS}$  is the drain-source voltage. Please note that calculating the switching loss is the most difficult part in the loss estimation. The formula above provides a simplified equation. For more accurate estimates, the equation becomes much more complex.

The total gate charge,  $Q_G$ , is used to calculate the gate drive loss. The expression is

$$P_{DR} \, = Q_G \times V_{DR} \times f_{SW}$$

Where  $V_{DR}$  is the drive voltage.

#### **Selecting the Output Capacitor**

The output capacitor keeps the output voltage ripple small and ensures feedback loop stability. The output capacitor impedance must be low at the switching frequency. Ceramic capacitors with X7R dielectrics are recommended for their low ESR characteristics. For most applications, a 4.7µF ceramic capacitor in parallel with a 22µF electrolytic capacitor will suffice.

#### **Setting the Over Voltage Protection**

The open string protection is achieved through the detection of the voltage on the OVP pin. In some cases, an LED string failure results in the feedback voltage always zero. The part then keeps boosting the output voltage higher and higher. If the output voltage reaches the programmed OVP threshold, OVP will trigger.

To ensure the chip functions properly, select the resistor values for the OVP resistor divider to provide an appropriate set voltage. The recommended OVP point is about 1.1 to 1.2 times higher than the output voltage for normal operation.

$$V_{\text{OVP}} = 1.23 \times \left(1 + \frac{R_{\text{HIGH}}}{R_{\text{LOW}}}\right)$$

#### **Selecting Dimming Control Mode**

The MP3397 provides two different dimming methods

#### 1. Direct PWM Dimming

An external PWM dimming signal is employed to achieve PWM dimming control. Connect a  $100k\Omega$  resistor from BOSC pin to GND and apply a PWM dimming signal—in the range of 100Hz to 20kHz—to the DBRT pin. The minimum recommended amplitude of the PWM signal is 1.2V. The low level should be less than 0.4V (See Figure 4).



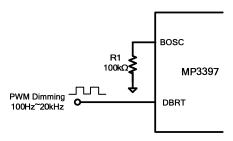


Figure 4—Direct PWM Dimming

Table 1 shows the PWM dimming duty Range with different PWM dimming frequency.

Tab 1 The Range of PWM Dimming Duty

f <sub>PWM</sub> (Hz)	D <sub>min</sub>	D <sub>max</sub>
100 <f≤200< td=""><td>0.30%</td><td>100%</td></f≤200<>	0.30%	100%
200 <f≤500< td=""><td>0.75%</td><td>100%</td></f≤500<>	0.75%	100%
500 <f≤1k< td=""><td>1.50%</td><td>100%</td></f≤1k<>	1.50%	100%
1k <f≤2k< td=""><td>3.00%</td><td>100%</td></f≤2k<>	3.00%	100%
2k <f≤5k< td=""><td>7.50%</td><td>100%</td></f≤5k<>	7.50%	100%
5k <f≤10k< td=""><td>15.00%</td><td>100%</td></f≤10k<>	15.00%	100%
10k <f≤20k< td=""><td>30.00%</td><td>100%</td></f≤20k<>	30.00%	100%

#### 2. DC Input PWM Dimming

For DC input PWM dimming, apply an analog signal (ranging from 0.2 V to 1.2V) to the DBRT pin to modulate the LED current directly. If the DBRT voltage falls below 0.2V, the PWM duty cycle will be 0%. If the DBRT voltage goes above 1.2V, the output will be 100% (See Figure 5). The capacitor on BOSC pin sets the frequency of the internal triangle waveform according to the equation.

$$f_{BOSC}(kHz) = 3.5 / C_{BOSC}(nF)$$

Chose a dimming frequency in the range of 100Hz to 20kHz.

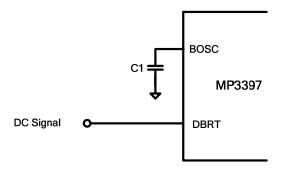


Figure 5—DC input PWM Dimming

#### **Expanding LED Channels**

The MP3397 can expand the number of LED channels by using two or three MP3397s in parallel. To connect two MP3397s for a total of 8 LED strings, tie the VCC pins of the master IC and the slave IC together to power the slave IC internal logic circuitry. Tie the COMP pins of the slave IC and the master IC together to regulate the voltage of all 8 strings LEDs. The slave IC MOSFET driving signals are not used; the boost converter can be only driven by the master IC. Do not leave the I<sub>SENSE</sub> pin of the slave IC floating; tie it to ground. Apply the EN and DIM signals to both ICs. For best results, use external PWM dimming mode for synchronized and accurate dimming.

#### **Layout Considerations**

The circuit layout for the MP3397 requires special attention to reduce EMI noise.

The loop from the external MOSFET (M1), through the output diode (D1) and the output capacitor (C2, C3) carry a high-frequency pulse current and must be as small and short as possible (See Figure 6).

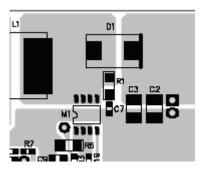


Figure 6—Layout Consideration

All logic signals return to the signal ground. In order to reduce the effects of noise, separate power ground (PGND) and signal ground (GND), and connect PGND and GND together through single point.



# **TYPICAL APPLICATION CIRCUIT**

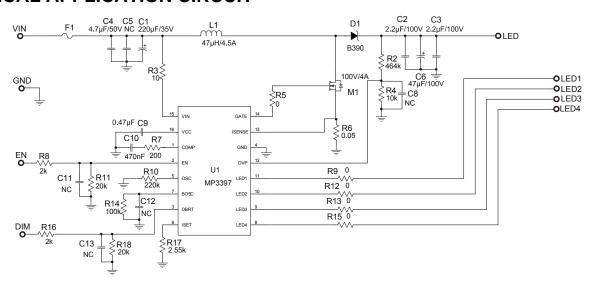
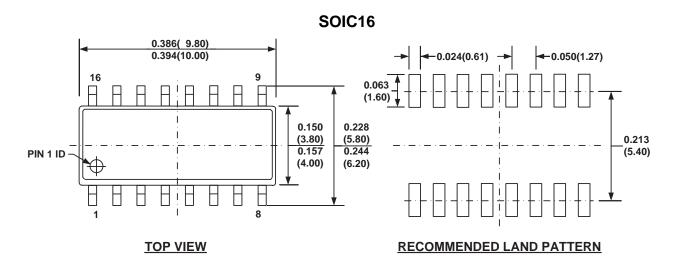
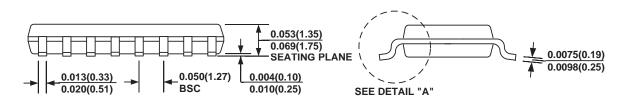


Figure 7—Drive 14 LEDs in Series, 4 Strings 330mA/string,10% D<sub>PWM</sub>

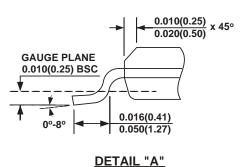


#### **PACKAGE INFORMATION**





**FRONT VIEW** 



NOTE:

- 1) CONTROL DIMENSION IS IN INCHES. DIMENSION IN BRACKET IS IN MILLIMETERS.
- 2) PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

**SIDE VIEW** 

- 3) PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
- 4) LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.004" INCHES MAX.
- 5) DRAWING CONFORMS TO JEDEC MS-012, VARIATION AC.
- 6) DRAWING IS NOT TO SCALE.

**NOTICE:** The information in this document is subject to change without notice. Users should warrant and guarantee that third party Intellectual Property rights are not infringed upon when integrating MPS products into any application. MPS will not assume any legal responsibility for any said applications.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for LED Lighting Drivers category:

Click to view products by Monolithic Power Systems manufacturer:

Other Similar products are found below:

LV5235V-MPB-H MB39C602PNF-G-JNEFE1 MIC2871YMK-T5 AL1676-10BS7-13 AL1676-20AS7-13 AP5726WUG-7 ICL8201
IS31BL3228B-UTLS2-TR IS31BL3506B-TTLS2-TR AL3157F-7 AP5725FDCG-7 AP5726FDCG-7 LV52204MTTBG AP5725WUG-7
STP4CMPQTR NCL30086BDR2G CAT4004BHU2-GT3 LV52207AXA-VH AP1694AS-13 TLE4242EJ AS3688 IS31LT3172-GRLS4-TR
TLD2311EL KTD2694EDQ-TR KTZ8864EJAA-TR IS32LT3174-GRLA3-TR MP2488DN-LF-Z NLM0010XTSA1 AL1676-20BS7-13
ZXLD1370QESTTC MPQ7220GF-AEC1-P MPQ7220GR-AEC1-P MPQ4425BGJ-AEC1-P MPQ7220GF-AEC1-Z MPQ7220GR-AEC1-Z
MPQ4425BGJ-AEC1-Z NCL30486A2DR2G IS31FL3737B-QFLS4-TR IS31FL3239-QFLS4-TR KTD2058EUAC-TR KTD2037EWE-TR
DIO5662ST6 IS31BL3508A-TTLS2-TR KTD2026BEWE-TR MAX20052CATC/V+ MAX25606AUP/V+ BD6586MUV-E2 BD9206EFV-E2 BD9416FS-E2 LYT4227E